

## LM390 1W Battery Operated Audio Power Amplifier

### General Description

The LM390 Power Audio Amplifier is optimized for 6V, 7.5V, 9V operation into low impedance loads. The gain is internally set at 20 to keep the external part count low, but the addition of an external resistor and capacitor between pins 2 and 6 will increase the gain to any value up to 200. The inputs are ground referenced while the output is automatically biased to one half the supply voltage.

### Features

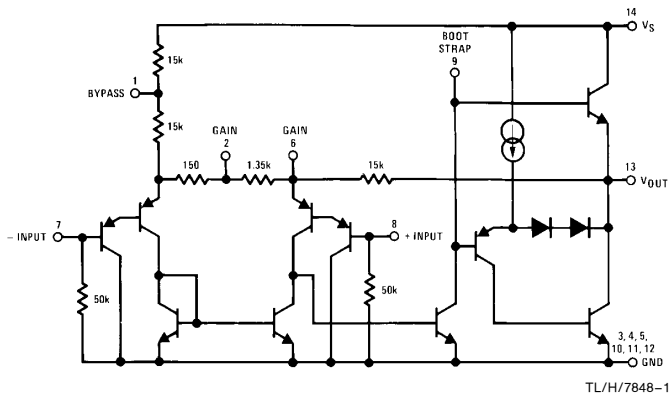
- Battery operation
- 1W output power
- Minimum external parts
- Excellent supply rejection
- Ground referenced input

- Self-centering output quiescent voltage
- Variable voltage gain
- Low distortion
- Fourteen pin dual-in-line package

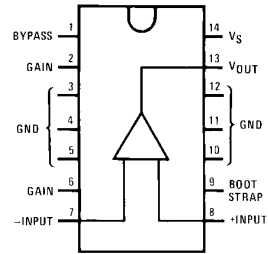
### Applications

- AM-FM radio amplifiers
- Portable tape player amplifiers
- Intercoms
- TV sound systems
- Lamp drivers
- Line drivers
- Ultrasonic drivers
- Small servo drivers
- Power converters

### Equivalent Schematic and Connection Diagrams



Dual-In-Line Package



Order Number **LM390N**  
See NS Package Number **N14A**

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	10V
Package Dissipation 14-Pin DIP (Note 1)	8.3W
Input Voltage	$\pm 0.4V$
Storage Temperature	$-65^{\circ}C$ to $+150^{\circ}C$

Operating Temperature	$0^{\circ}C$ to $+70^{\circ}C$
Junction Temperature	$150^{\circ}C$
Lead Temperature (Soldering, 10 sec.)	$260^{\circ}C$
Thermal Resistance	
$\theta_{JC}$	$30^{\circ}C/W$
$\theta_{JA}$	$79^{\circ}C/W$

## Electrical Characteristics $T_A = 25^{\circ}C$ , (Figure 1)

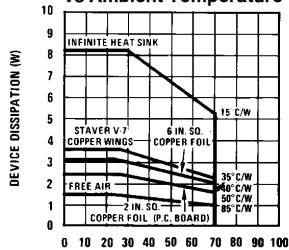
Symbol	Parameter	Conditions	Min	Typ	Max	Units
$V_S$	Operating Supply Voltage		4		9	V
$I_Q$	Quiescent Current	$V_S = 6V$ , $V_{IN} = 0$		10	20	mA
$P_{OUT}$	Output Power	$V_S = 6V$ , $R_L = 4\Omega$ , THD = 10%	0.8	1.0		W
$A_V$	Voltage Gain	$V_S = 6V$ , $f = 1\text{ kHz}$ $10\ \mu F$ from Pin 2 to 6	23	26 46	30	dB dB
BW	Bandwidth	$V_S = 6V$ , Pins 2 and 6 Open		300		kHz
THD	Total Harmonic Distortion	$V_S = 6V$ , $R_L = 4\Omega$ , $P_{OUT} = 500\text{ mW}$ $f = 1\text{ kHz}$ , Pins 2 and 6 Open		0.2	1	%
PSRR	Power Supply Rejection Ratio	$V_S = 6V$ , $f = 1\text{ kHz}$ , $C_{BYPASS} = 10\ \mu F$ , Pins 2 and 6 Open, Referred to Output (Note 2)		50		dB
$R_{IN}$	Input Resistance		10	50		$k\Omega$
$I_{BIAS}$	Input Bias Current	$V_S = 6V$ , Pins 7 and 8 Open		250		nA

Note 1: Pins 3, 4, 5, 10, 11, 12 at  $25^{\circ}C$ . Above  $25^{\circ}C$  case, derate at  $15^{\circ}C/W$  junction to case, or  $85^{\circ}C/W$  junction to ambient.

Note 2: If load and bypass capacitor are returned to  $V_S$  (Figure 2), rather than ground (Figure 1), PSRR is typically 30 dB.

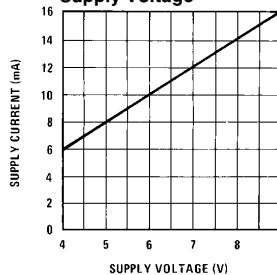
## Typical Performance Characteristics

Maximum Device Dissipation vs Ambient Temperature

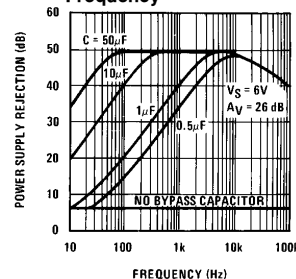


$T_A$  - AMBIENT TEMPERATURE ( $^{\circ}C$ )  
Note: 2 oz. copper foil, single-sided PC board.

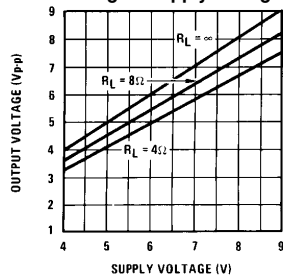
Quiescent Supply Current vs Supply Voltage



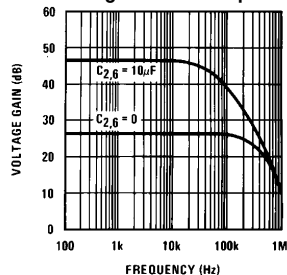
Power Supply Rejection Ratio (Referred to the Output) vs Frequency



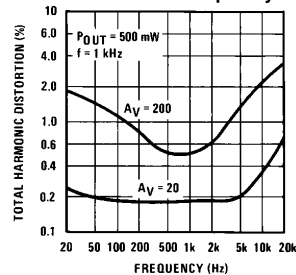
Peak-to-Peak Output Voltage Swing vs Supply Voltage



Voltage Gain vs Frequency



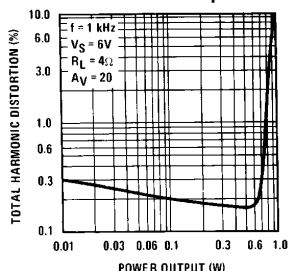
Distortion vs Frequency



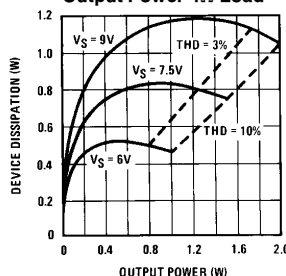
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## Typical Performance Characteristics (Continued)

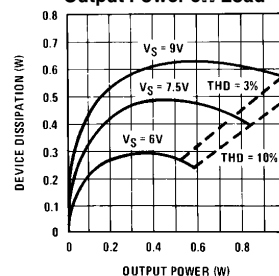
Distortion vs Output Power



Device Dissipation vs Output Power 4Ω Load



Device Dissipation vs Output Power 8Ω Load



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## Application Hints

### Gain Control

To make the LM390 a more versatile amplifier, two pins (2 and 6) are provided for gain control. With pins 2 and 6 open, the 1.35 kΩ resistor sets the gain at 20 (26 dB). If a capacitor is put from pin 2 to 6, bypassing the 1.35 kΩ resistor, the gain will go up to 200 (46 dB). If a resistor is placed in series with the capacitor, the gain can be set to any value from 20 to 200. A low frequency pole in the gain response is caused by the capacitor working against the external resistor in series with the 150Ω internal resistor. If the capacitor is eliminated and a resistor connects pin 2 to 6 then the output dc level may shift due to the additional dc gain. Gain control can also be done by capacitively coupling a resistor (or FET) from pin 6 to ground, as in Figure 7.

Additional external components can be placed in parallel with the internal feedback resistors to tailor the gain and frequency response for individual applications. For example, we can compensate poor speaker bass response by frequency shaping the feedback path. This is done with a series RC from pin 6 to 13 (paralleling the internal 15 kΩ resistor). For 6 dB effective bass boost:  $R \approx 15 \text{ k}\Omega$ , the lowest value for good stable operation is  $R = 10 \text{ k}\Omega$  if pin 2 is open. If pins 2 and 6 are bypassed then  $R$  as low as 2 kΩ can be used. This restriction is because the amplifier is only compensated for closed-loop gains greater than 9 V/V.

### Input Biasing

The schematic shows that both inputs are biased to ground with a 50 kΩ resistor. The base current of the input transistors is about 250 nA, so the inputs are at about 12.5 mV when left open. If the dc source resistance driving the LM390 is higher than 250 kΩ it will contribute very little additional offset (about 2.5 mV at the input, 50 mV at the output). If the dc source resistance is less than 10 kΩ, then shorting the unused input to ground will keep the offset low (about 2.5 mV at the input 50 mV at the output). For dc source resistances between these values we can eliminate excess offset by putting a resistor from the unused input to ground, equal in value to the dc source resistance. Of course all offset problems are eliminated if the input is capacitively coupled.

When using the LM390 with higher gains (bypassing the 1.35 kΩ resistor between pins 2 and 6) it is necessary to

bypass the unused input, preventing degradation of gain and possible instabilities. This is done with a 0.1 μF capacitor or a short to ground depending on the dc source resistance on the driven input.

### Bootstrapping

The base of the output transistor of the LM390 is brought out to pin 9 for Bootstrapping. The output stage of the amplifier during positive swing is shown in Figure 3 with its external circuitry.

$R1 + R2$  set the amount of base current available to the output transistor. The maximum output current divided by beta is the value required for the current in  $R1$  and  $R2$ :

$$(R1 + R2) = \beta_O \frac{(V_S/2) - V_{BE}}{I_{O \text{ MAX}}}$$

Good design values are  $V_{BE} = 0.7\text{V}$  and  $\beta_O = 100$ .

Example 0.8 watt into 4Ω load with  $V_S = 6\text{V}$ .

$$I_{O \text{ MAX}} = \sqrt{\frac{2 P_O}{R_L}} = 632 \text{ mA}$$

$$(R1 + R2) = 100 \left( \frac{(6/2) - 0.7}{0.632} \right) = 364\Omega$$

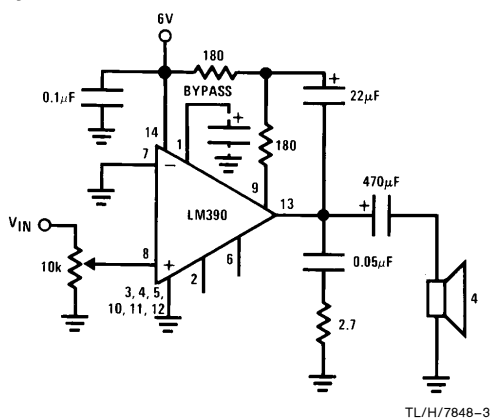
To keep the current in  $R2$  constant during positive swing capacitor  $C_B$  is added. As the output swings positive  $C_B$  lifts  $R1$  and  $R2$  above the supply, maintaining a constant voltage across  $R2$ . To minimize the value of  $C_B$ ,  $R1 = R2$ . The pole due to  $C_B$  and  $R1$  and  $R2$  is usually set equal to the pole due to the output coupling capacitor and the load. This gives:

$$C_B \approx \frac{4C_C}{\beta_O} \approx \frac{C_C}{25}$$

Example: for 100 Hz pole and  $R_L = 4\Omega$ ;  $C_C = 400 \mu\text{F}$  and  $C_B = 16 \mu\text{F}$ , if  $R1$  is made a diode and  $R2$  increased to give the same current,  $C_B$  can be decreased by about a factor of 4, as in Figure 4.

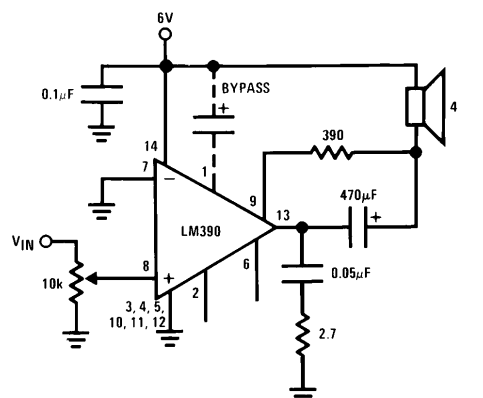
For reduced component count the load can replace  $R1$ . The value of  $(R1 + R2)$  is the same, so  $R2$  is increased. Now  $C_B$  is both the coupling and the bootstrapping capacitor (see Figure 2).

## Typical Applications



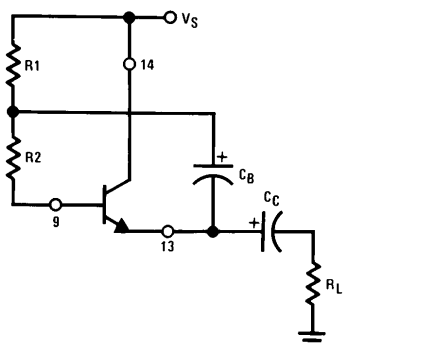
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**FIGURE 1. Load Returned to Ground  
(Amplifier with Gain = 20)**



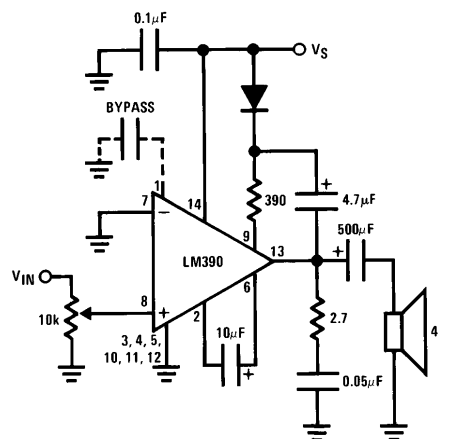
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**FIGURE 2. Load Returned to Supply  
(Amplifier with Gain = 20)**



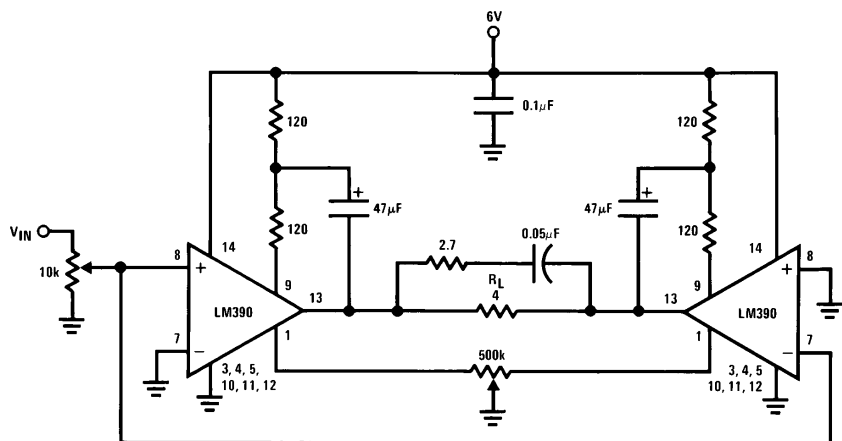
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**FIGURE 3**



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**FIGURE 4. Amplifier with Gain = 200 and Minimum  $C_B$**



**FIGURE 5. 2.5W Bridge Amplifier**

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## Typical Applications (Continued)

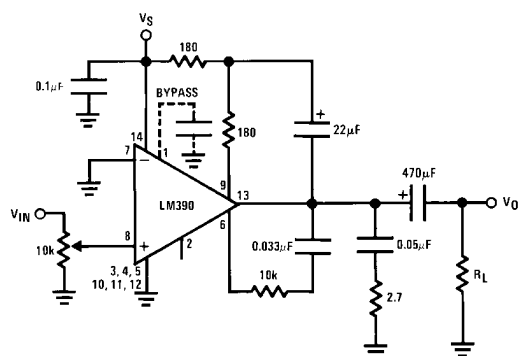
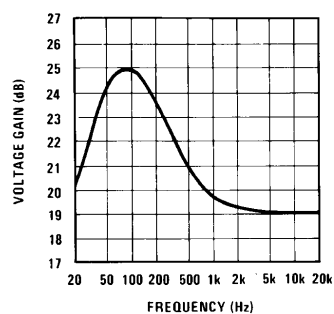


FIGURE 6(a). Amplifier with Bass Boost

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TL/H/7848-11

FIGURE 6(b). Frequency Response with Bass Boost

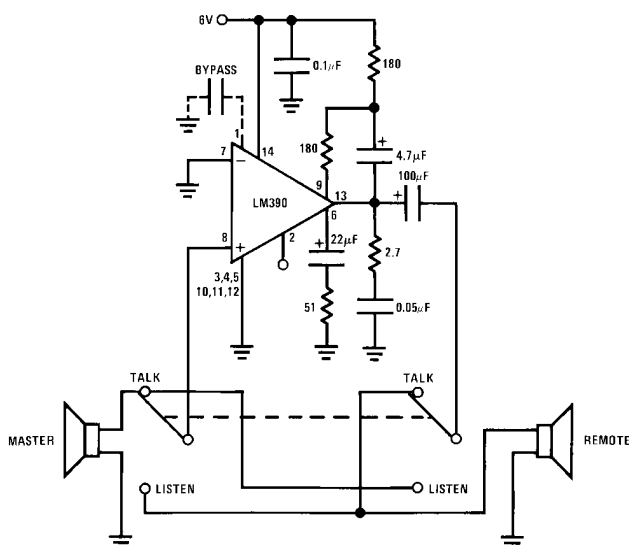


FIGURE 7. Intercom

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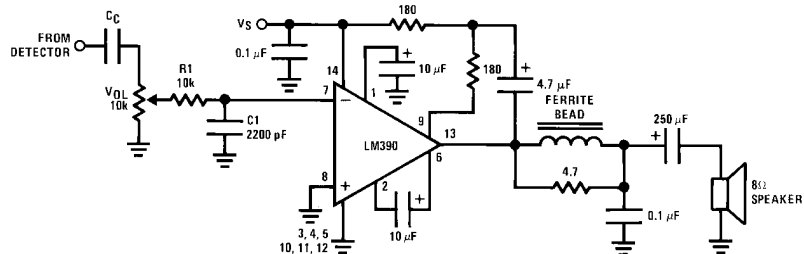


FIGURE 8. AM Radio Power Amplifier

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**Note 1:** Twist supply lead and supply ground very tightly.

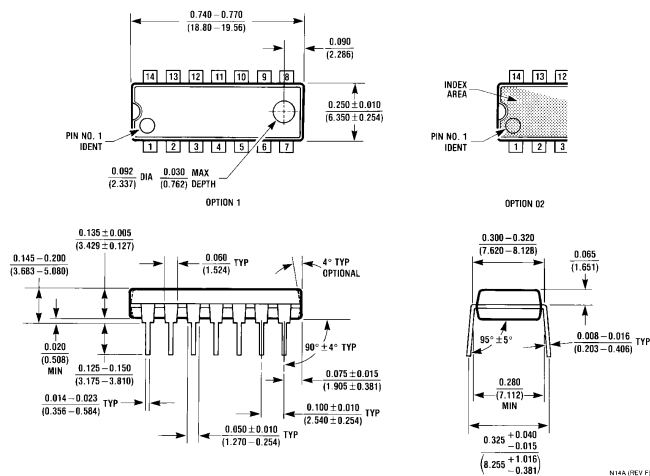
**Note 2:** Twist speaker lead and ground very tightly.

**Note 3:** Ferrite bead is Ferroxcube K5-001-001/3B with 3 turns of wire.

**Note 4:** R1C1 band limits input signals.

**Note 5:** All components must be spaced very close to IC.

Physical Dimensions inches (millimeters)




Molded Dual-In-Line Package (N)  
Order Number LM390N  
See NS Package Number N14A

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